



POWERFUL LASER SYSTEM
FOR MICRO MATERIAL PROCESSING

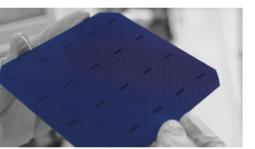


## **FEATURES**

- Single or dual scanner setup
- Automatic calibration routines
- Automated process control
- Stand alone and production line integrated systems
- 3-, 5- or even 8-Point alignment methods available (wafer edges or fiducials)

## **OPTIONS**

- CAD file import
- SQL data base for process and event tracking
- MES interface (SECS GEM PV2)
- Integrated process metrology
- Fully-automatic handling (production)







APPLICATIONS Laser Contact Opening for PERC, Laser Doped Selective

Emitter, Front side LCO, various applications in electronics

processing

ACCURACY  $< +/-35 \mu m (1 sigma)$ 

< +/-10 μm optionally

< +/-2 µm repeatability

SUBSTRATE Dimension up to 161 x 161 mm

Thickness > 100 μm

mono or poly crystalline silicon square/ pseudo square,

ceramic, PCB

AVAILABLE LASER SOURCES Wavelength: 1064, 1030, 532, 515, 355 nm

Pulse: µs, ns, ps, fs

THROUGHPUT 4000 wafer per hour

